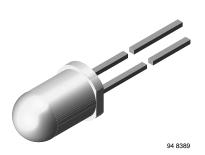
GREEN

(5-2008)<sup>1</sup>



## Vishay Semiconductors

# High Speed Infrared Emitting Diode, 830 nm, GaAlAs Double Hetero



### **DESCRIPTION**

TSHG8200 is an infrared, 830 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

#### **FEATURES**

Package type: leadedPackage form: T-1¾

Dimensions (in mm): Ø 5

• Peak wavelength:  $\lambda_p = 830 \text{ nm}$ 

· High reliability

· High radiant power

High radiant intensity

• Angle of half intensity:  $\varphi = \pm 10^{\circ}$ 

· Low forward voltage

- · Suitable for high pulse current operation
- High modulation bandwidth: f<sub>c</sub> = 18 MHz
- · Good spectral matching with CMOS cameras
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Note

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

#### **APPLICATIONS**

- Infrared radiation source for operation with CMOS cameras (illumination)
- High speed IR data transmission
- · Smoke-automatic fire detectors

PRODUCT SUMMARY					
COMPONENT	I <sub>e</sub> (mW/sr)	φ (deg)	$\lambda_{\mathbf{P}}$ (nm)	tr (ns)	
TSHG8200	180	± 10	830	20	

#### Note

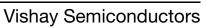
• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSHG8200	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		

#### Note

· MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		$V_{R}$	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А	
Power dissipation		P <sub>V</sub>	180	mW	
Junction temperature		T <sub>j</sub>	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	t ≤ 5 s, 2 mm from case	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm soldered on PCB	R <sub>thJA</sub>	230	K/W	





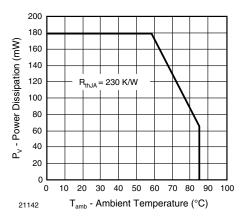


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

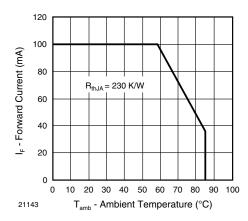


Fig. 1 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>		1.5	1.8	V
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	V <sub>F</sub>		2.3		V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		- 1.8		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μA
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0$	C <sub>j</sub>		125		pF
B. F	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	120	180	360	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l <sub>e</sub>		1600		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		50		mW
Temperature coefficient of φ <sub>e</sub>	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		- 0.35		%/K
Angle of half intensity		φ		± 10		deg
Peak wavelength	I <sub>F</sub> = 100 mA	λρ		830		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		40		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	TKλ <sub>p</sub>		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA	t <sub>r</sub>		20		ns
Fall time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		13		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f <sub>c</sub>		18		MHz
Virtual source diameter		d		3.7		mm



## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

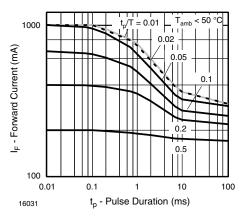


Fig. 2 - Pulse Forward Current vs. Pulse Duration

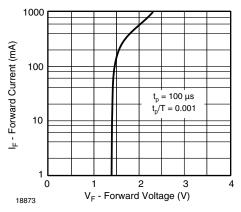


Fig. 3 - Forward Current vs. Forward Voltage

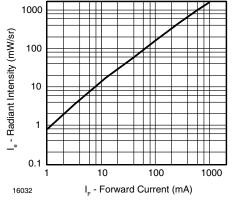


Fig. 4 - Radiant Intensity vs. Forward Current

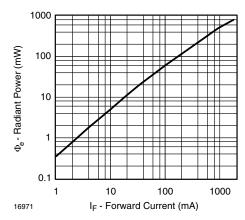


Fig. 5 - Radiant Power vs. Forward Current

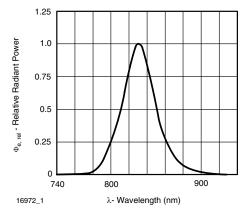


Fig. 6 - Relative Radiant Power vs. Wavelength

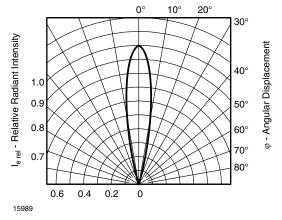
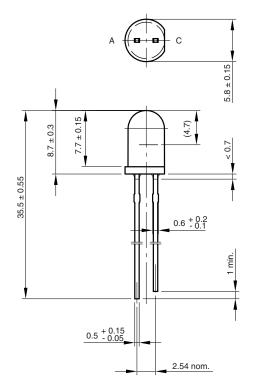
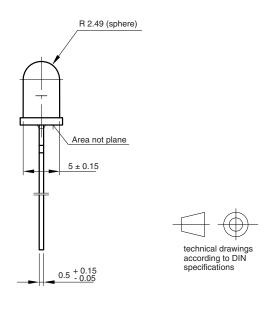


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

# Vishay Semiconductors

#### **PACKAGE DIMENSIONS** in millimeters





6.544-5259.02-4 Issue: 8; 19.05.09 95 10917



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Revision: 02-Oct-12 Document Number: 91000

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